To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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DATA SHEET

RENESAS

SILICON TRANSISTOR
2SA1611

AUDIO FREQUENCY, GENERAL PURPOSE AMPLIFIER
PNP SILICON EPITAXIAL TRANSISTOR

FEATURES

- Complementary to 2SC4177
- High DC Current Gain: h_{FE} = 200 TYP. (V_{CE} = –6.0 V, I_C = –1.0 mA)
- High Voltage: V_{CEO} = –50 V

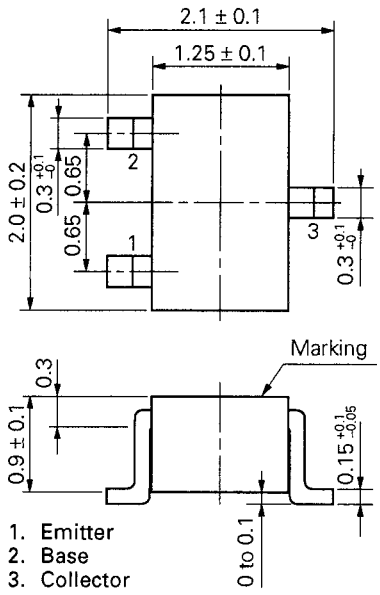
QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DIMENSIONS

in millimeters



ABSOLUTE MAXIMUM RATINGS (T_a = 25 °C)

Collector to Base Voltage	V_{CBO}	–60	V
Collector to Emitter Voltage	V_{CEO}	–50	V
Emitter to Base Voltage	V_{EBO}	–5.0	V
Collector Current (DC)	I_C	–100	mA
Total Power Dissipation	P_T	150	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	–55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			–0.1	μA	V_{CB} = –60 V, I_E = 0
Emitter Cutoff Current	I_{EBO}			–0.1	μA	V_{EB} = –5.0 V, I_C = 0
DC Current Gain	h_{FE}	90	200	600		V_{CE} = –6.0 V, I_C = –1.0 mA*
Collector Saturation Voltage	$V_{CE(sat)}$		–0.18	–0.3	V	I_C = –100 mA, I_B = –10 mA
Base to Emitter Voltage	V_{BE}	–0.58	–0.62	–0.68	V	V_{CE} = –6.0 V, I_C = –1.0 mA
Gain Bandwidth Product	f_T		180		MHz	V_{CE} = –6.0 V, I_E = 10 mA
Output Capacitance	C_{ob}		4.5		pF	V_{CB} = –10 V, I_E = 0, f = 1.0 MHz

* Pulsed: PW ≦ 350 μs, Duty Cycle ≦ 2 %

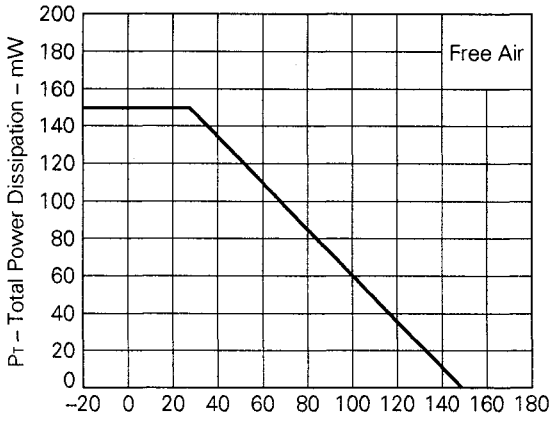
h_{FE} Classification

Marking	M4	M5	M6	M7
h_{FE}	90 to 180	135 to 270	200 to 400	300 to 600

Document No. TC-2115A
(O.D. No. TC-6209)
Date Published August 1993 M
Printed in Japan

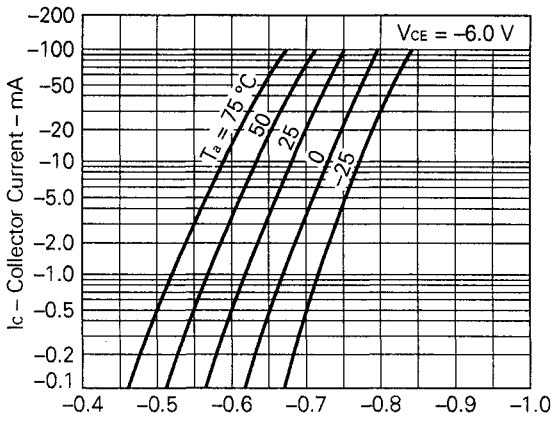
TYPICAL CHARACTERISTICS (T_a = 25 °C)

TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



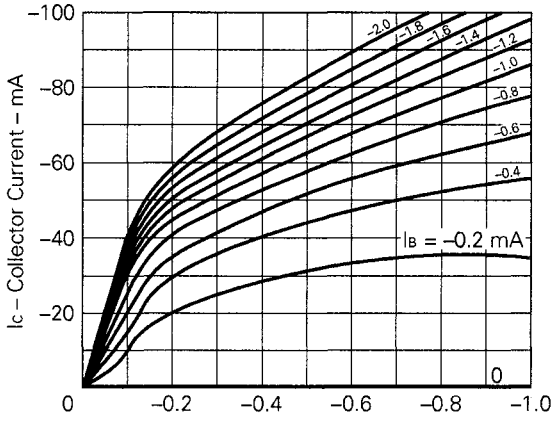
Ta – Ambient Temperature – °C

COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



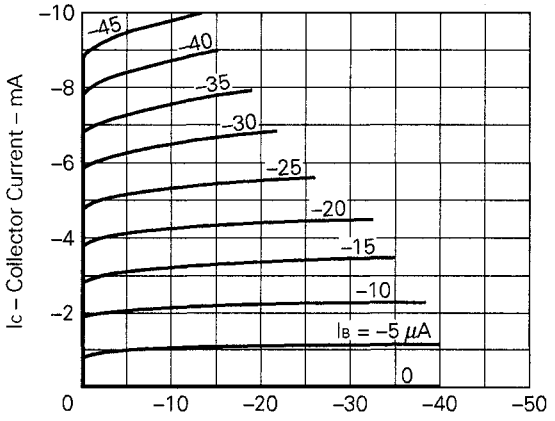
VBE – Base to Emitter Voltage – V

COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



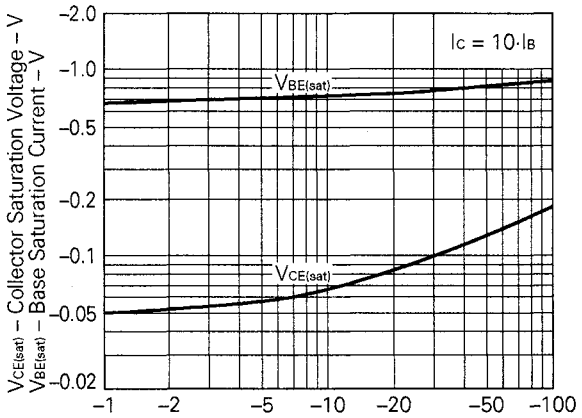
VCE – Collector to Emitter Voltage – V

COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



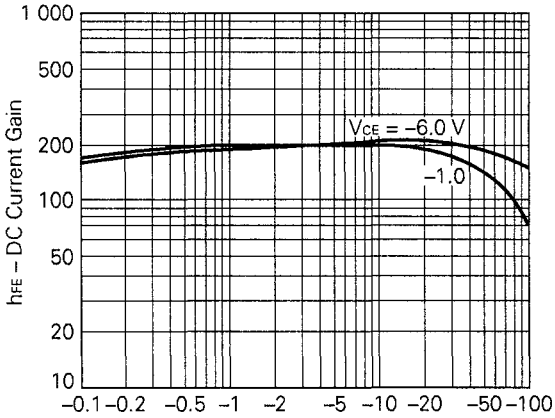
VCE – Collector to Emitter Voltage – V

BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



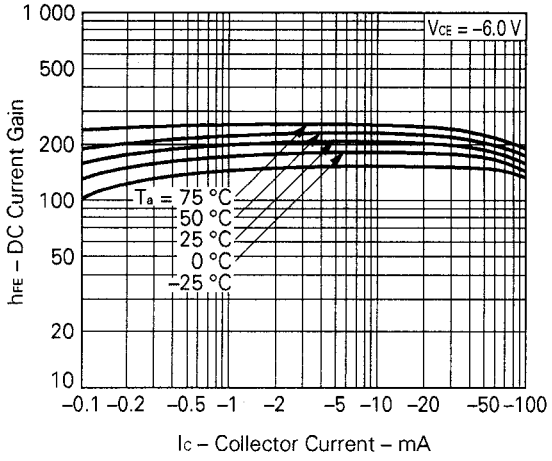
IC – Collector Current – mA

DC CURRENT GAIN vs. COLLECTOR CURRENT

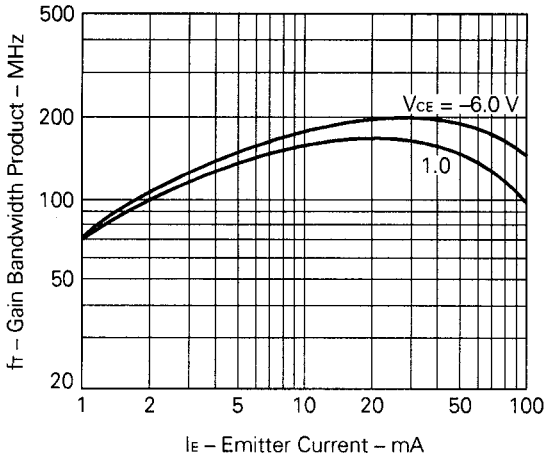


IC – Collector Current – mA

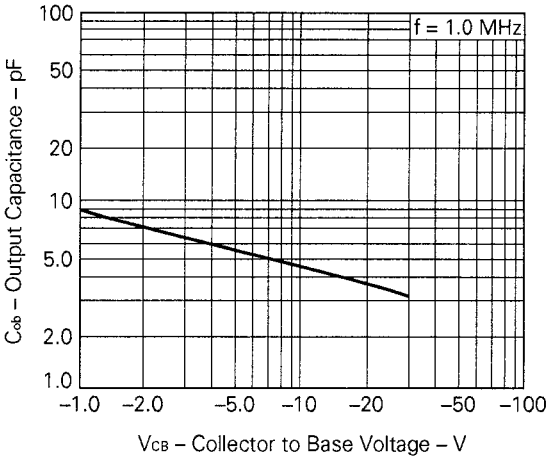
DC CURRENT GAIN vs.
COLLECTOR CURRENT



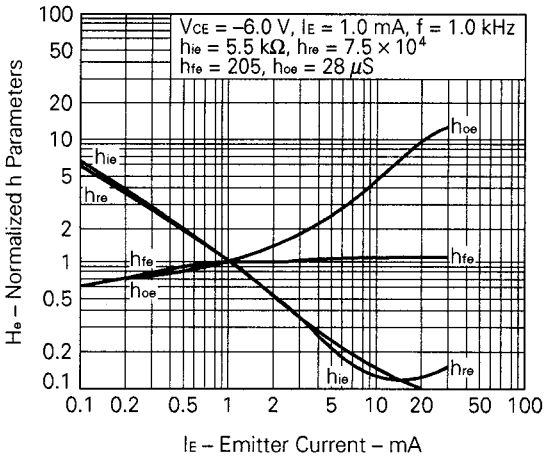
GAIN BANDWIDTH PRODUCT vs.
EMITTER CURRENT



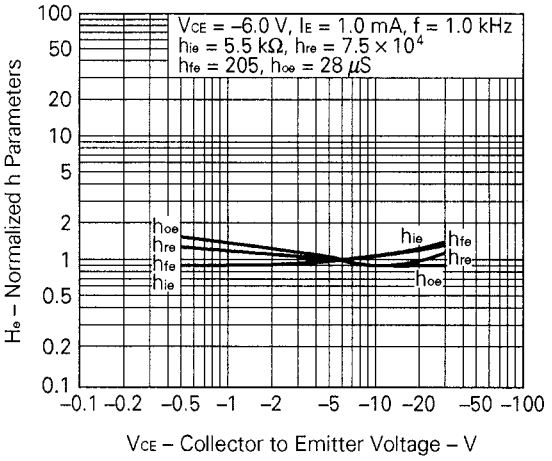
OUTPUT CAPACITANCE vs.
REVERSE VOLTAGE



NORMALIZED h PARAMETER vs.
EMITTER CURRENT



NORMALIZED h PARAMETER vs.
COLLECTOR TO EMITTER VOLTAGE



REFERENCE APPLICATION NOTE

ASSEMBLY MANUAL FOR SEMICONDUCTOR DEVICES	IEI-1207
QUALITY CONTROL OF NEC SEMICONDUCTOR DEVICES	TEI-1202
QUALITY CONTROL GUIDE OF SEMICONDUCTOR DEVICES	MEI-1202

M4 92.6

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